NSN 5962-01-034-9826

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View Online at https://aerobasegroup.com/nsn/5962-01-034-9826

Body	Length:
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Between 1.190 inches and 1.230 inches

Body Width:

Between 0.580 inches and 0.610 inches

Body Height:

Between 0.080 inches and 0.120 inches

Maximum Power Dissipation Rating:

805.0 milliwatts

Operating Tempurature Range:

+0.0/+75.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

Multiplexer fscm 52483

Features Provided:

Hermetically sealed and monolithic and high speed and schottky and w/enable and w/disable and w/strobe and w/register output and programmable and programmed and 3-state output and w/buffered output and w/decoded output

Inclosure Material:

Ceramic and metal

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

12 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

5.5 volts power source

Time Rating Per Chacteristic:

40.00 nanoseconds propagation delay time, low to high level output and 35.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Rom

Precious Material And Location:

Terminals gold

Precious Material:

Gold

Test Data Document:

52483-104228 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

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Demilitarization:

Yes - demil/mli

Fiig:

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